

Ex (5.1) Page (257)

$$L = 0.18 \mu\text{m} \quad t_{ox} = 4 \text{ nm} \quad \mu_n = 450 \text{ cm}^2/\text{V}$$

$$V_t = 0.5 \text{ V} \quad \epsilon_{ox} = 3.45 \times 10^{-11} \text{ F/m}$$

a) find: C_{ox} and $K'_n \rightarrow$ Process transconductance Parameter

$$C_{ox} = \frac{\epsilon_{ox}}{t_{ox}} = \frac{3.45 \times 10^{-11}}{4 \times 10^{-9}} = 8.63 \times 10^{-3} \text{ F/m}^2$$

$$K'_n = \mu_n C_{ox} = 450 \times 10^4 (8.63 \times 10^{-3}) = 388.35 \times 10^6 \text{ F/V} = 388 \mu\text{A/V}^2$$

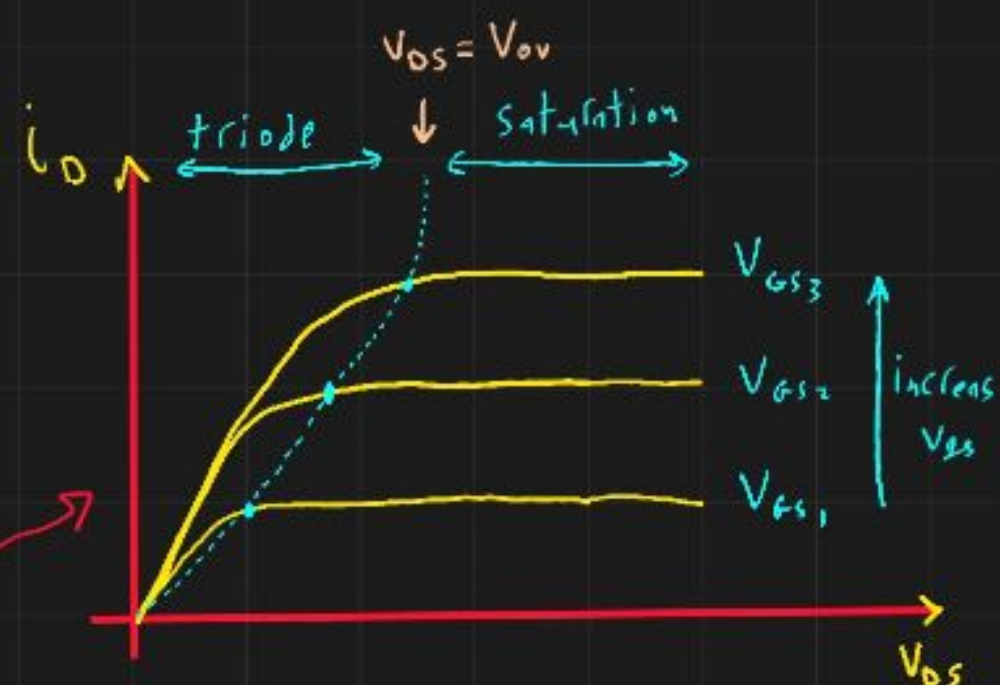
b) $\frac{W}{L} = \frac{1.8 \mu\text{m}}{0.18 \mu\text{m}}$ Calculate V_{ov} , V_{gs} and V_{ds} in saturation $i_D = 100 \mu\text{A}$

$$\rightarrow \therefore i_D = \frac{1}{2} K'_n \left(\frac{W}{L}\right) (V_{ov})^2$$

$$\therefore 100 \mu\text{A} = \frac{1}{2} (388 \mu\text{A}) \left(\frac{1.8}{0.18}\right) (V_{ov})^2 \rightarrow \therefore V_{ov} = 0.23 \text{ V}$$

$$\rightarrow \therefore V_{ov} = V_{gs} - V_t \rightarrow \therefore 0.23 = V_{gs} - 0.5 \rightarrow \therefore V_{gs} = 0.73 \text{ V}$$

$$\rightarrow V_{ds_{min}} = V_{ov} = 0.23 \text{ V} \text{ Why?}$$



c) for device in (b) find V_{ov} , V_{gs} to operate as a 1000 Ω resistor for small V_{ds}

in the triode region

small signal model

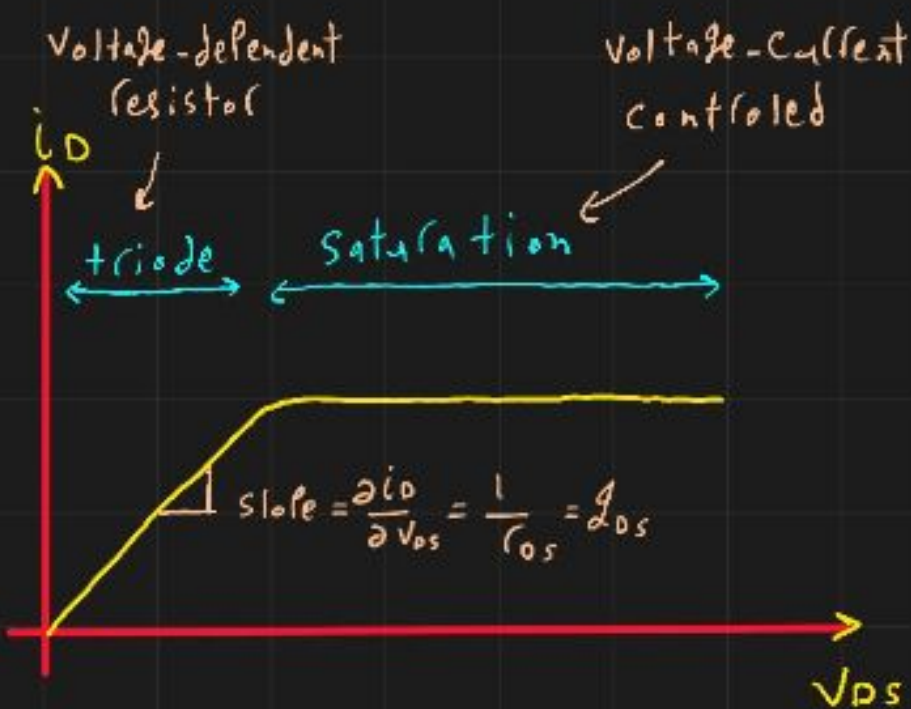
$$\rightarrow \text{in triode region } i_D = K'_n (V_{ov} V_{ds} - \frac{1}{2} V_{ds}^2)$$

$$\therefore g_{ds} = \frac{\partial i_D}{\partial V_{ds}} \rightarrow \therefore g_{ds} = K'_n V_{ov} = K'_n \left(\frac{W}{L}\right) V_{ov}$$

$$\therefore g_{ds} = \frac{1}{r_{ds}} \rightarrow \therefore g_{ds} = \frac{1}{1000}$$

$$\therefore \frac{1}{1000} = K'_n \left(\frac{W}{L}\right) V_{ov}$$

$$\therefore \frac{1}{1000} = 388 \times 10^6 \times 10 (V_{ov}) \rightarrow \therefore V_{ov} = 0.26 \text{ V}$$



Small
 * large signal model in saturation
 Voltage Control Current Source

oxide layer I_G I_D V_{GS} $V_{DS} \rightarrow V_{ov}$

Saturation $I_D = \frac{K_n}{2} (V_{GS} - V_t)^2$

Ex (5.2) Page (265)

NMOS

$W = 2 \mu m$ $L = 0.18 \mu m$ $C_{ox} = 8.6 \text{ fF}/\mu m^2$

$\mu_n = 450 \text{ cm}^2/\text{V.s}$ $V_{tn} = 0.5 \text{ V}$

a) find : $I_D = 100 \mu A$ V_{GS} , V_{DS} saturation

$$\therefore I_D = \frac{1}{2} K_n (V_{GS} - V_t)^2 = \frac{1}{2} (\mu C_{ox}) \left(\frac{W}{L} \right) (V_{GS} - V_{th})^2$$

$$\therefore 100 \times 10^{-6} = \frac{1}{2} (450 \times 10^4 \times 8.6 \times \frac{10^{-15}}{10^{-12}}) \left(\frac{2 \times 10^{-6}}{0.18 \times 10^{-6}} \right) (V_{GS} - 0.5)^2$$

$$\therefore V_{GS} = 0.72 \text{ V}$$

$$\therefore V_{DS} = V_{ov} = 0.72 - 0.5$$

$$\therefore V_{DS} = 0.22 \text{ V}$$

b) V_{GS} kept Const find V_{DS} at $I_D = 50 \mu A$

$\therefore V_{GS}$ is kept constant $\therefore V_{ov}$ is the same too.

$\rightarrow 50 \mu A$ is more likely to be in the triode region.

$$\therefore I_D = K_n (V_{ov} V_{DS} - \frac{1}{2} V_{DS}^2)$$

$$\therefore 50 \times 10^{-6} = 4.3 \times 10^{-3} [0.22 V_{DS} - \frac{1}{2} V_{DS}^2]$$

$$\therefore V_{DS} = 0.06 \text{ V}$$

$$V_{DS} < V_{ov} \checkmark$$

accepted

$$\therefore V_{DS} = 0.39 \text{ V}$$

$$V_{DS} > V_{ov} \times$$

rejected \rightarrow in triode $V_{DS} < V_{ov}$

\therefore operates in the triode region.

